

VERTICAL DEFLECTION BOOSTER

FEATURES SUMMARY

- POWER AMPLIFIER
- THERMAL PROTECTION
- OUTPUT CURRENT UP TO 2.6A_{PP}
- FLYBACK VOLTAGE UP TO 90V (on Pin 5)
- SUITABLE FOR DC COUPLING APPLICATION
- EXTERNAL FLYBACK SUPPLY

DESCRIPTION

Designed for monitors and high performance TVs, the STV9379FA vertical deflection booster can handle flyback voltage up to 90V. Further to this, it is possible to have a flyback voltage which is more than the double of the supply (Pin 2). This allows to decrease the power consumption, or to decrease the flyback time for a given supply voltage.

The STV9379FA operates with supplies up to 42V and provides up to 2.6A_{PP} output current to drive the yoke.

The STV9379FA is offered in HEPTAWATT package.

Figure 1. Package

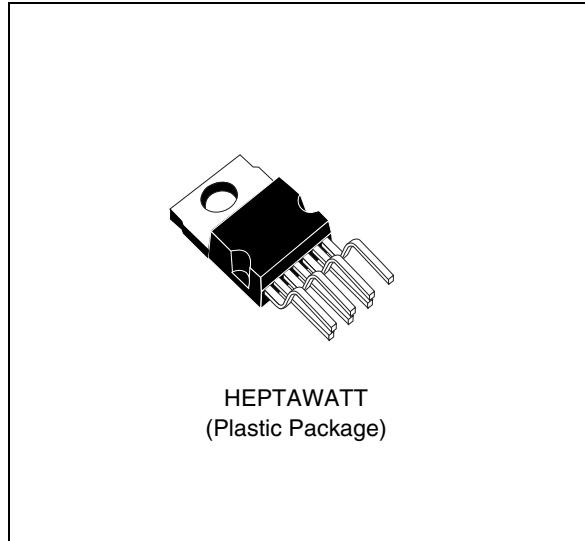
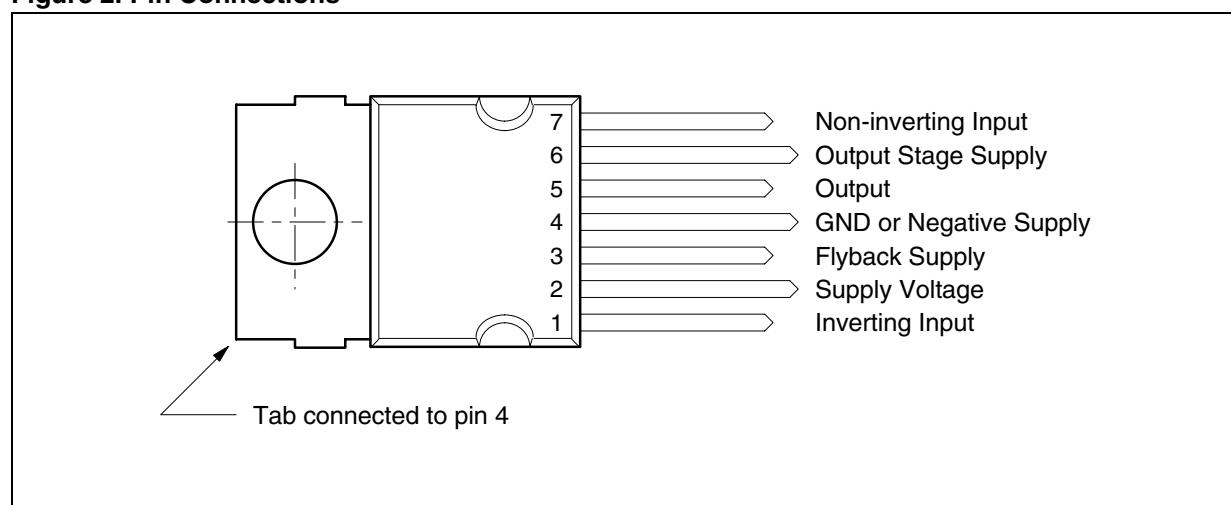


Figure 2. Pin Connections



STV9379FA

Figure 3. Block Diagram

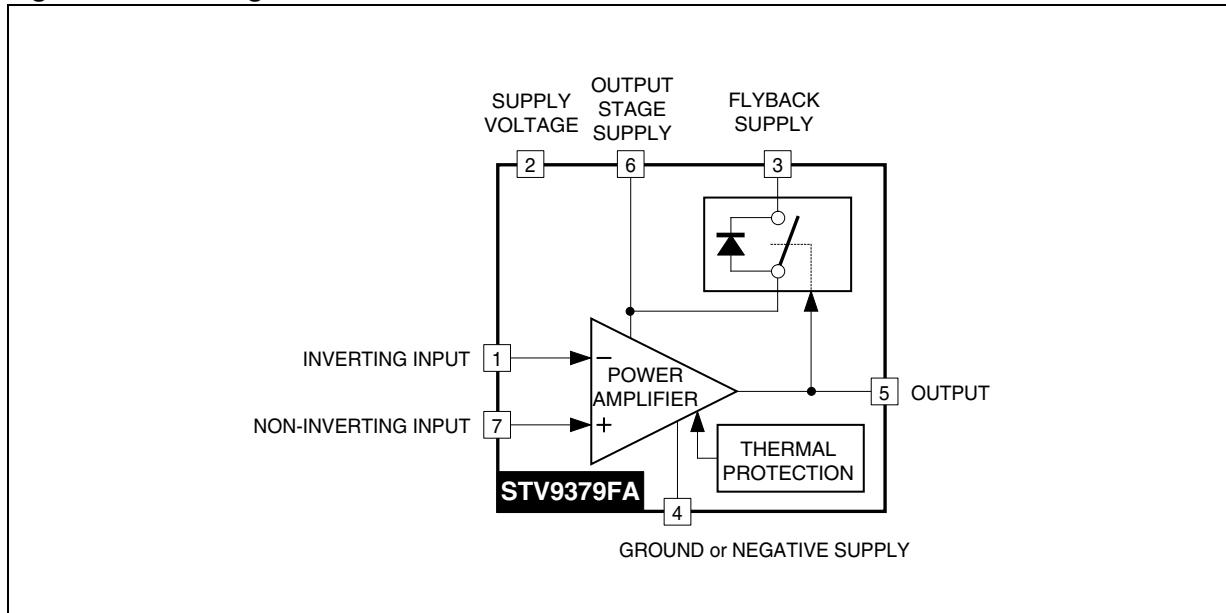


Table 1. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_S	Supply Voltage (Pin 2) (see note 1)	50	V
V_6	Flyback Peak Voltage (Pin 6) (see note 1)	100	V
V_1, V_7	Amplifier Input Voltage (Pins 1-7) (see note 1)	- 0.3, + V_S	V
I_O	Maximum Output Peak Current (see notes 2 and 3)	1.8	A
I_3	Maximum Sink Current ($t < 1\text{ms}$)	1.8	A
I_3	Maximum Source Current ($t < 1\text{ms}$) (in the diode, see Block Diagram) (see note 2)	1.8	A
V_{ESD}	ESD susceptibility : EIAJ Norm (200pF discharged through 0Ω)	300	V
$V_3 - V_2$	Voltage Difference between Flyback Supply and Supply Voltage	50	V
T_{OPER}	Operating Ambient Temperature	- 20, + 75	°C
$T_{STG,}$	Storage Temperature	- 40, + 150	°C
T_j	Junction Temperature	+ 150	°C

Note: 1. Versus Pin 4.

2. The output current can reach 5A peak for $t \leq 10\mu\text{s}$ (up to 120Hz).

3. Provided SOAR is respected (see Figures 6 and 7).

Table 2. Thermal Data

Symbol	Parameter	Value	Unit
R_{th} (j-c)	Junction-case Thermal Resistance Max	3	°C/W
T_t	Temperature for Thermal Shutdown	150	°C
ΔT_t	Hysteresis on T_t	10	°C
T_{jr}	Recommended Max. Junction Temperature	120	°C

Table 3. ELECTRICAL CHARACTERISTICS
($V_S = 42V$, $T_A = 25^\circ C$, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_S	Operating Supply Voltage Range	Versus Pin 4	10		42	V
V_{3M}	Operating Flyback Supply Voltage ($V_{3M} \leq V_S + 50V$)	Versus Pin 4	V_S		70	V
I_2	Pin 2 Quiescent Current	$I_3 = 0, I_5 = 0$		13	20	mA
I_6	Pin 6 Quiescent Current	$I_3 = 0, I_5 = 0$	5	10	30	mA
I_O	Max. Operating Peak Output Current				1.3	A
I_1	Amplifier Bias Current	$V_1 = 22V, V_7 = 23V$		- 0.15	- 1	µA
I_7	Amplifier Bias Current	$V_1 = 23V, V_7 = 22V$		- 0.15	- 1	µA
V_{IO}	Offset Voltage				7	mV
$\Delta V_{IO} /dt$	Offset Drift versus Temperature			- 10		µV/°C
GV	Voltage Gain		80			dB
V_{5L}	Output Saturation Voltage to GND (Pin 4)	$I_5 = 1.3A$		1	1.6	V
V_{5H}	Output Saturation Voltage to Supply (Pin 6)	$I_5 = - 1.3A$		1.6	2.2	V
V_{D5-6}	Diode Forward Voltage between Pins 5-6	$I_5 = 1.3A$		1.4	2.1	V
V_{D3-6}	Diode Forward Voltage between Pins 3-6	$I_3 = 1.3A$		1.7	2.5	V
V_{3-6}	Voltage Drop between Pins 3-6 (2nd part of flyback)	$I_3 = - 1.3A$		2.9	3.6	V

STV9379FA

APPLICATION CIRCUITS

Figure 4. AC Coupling

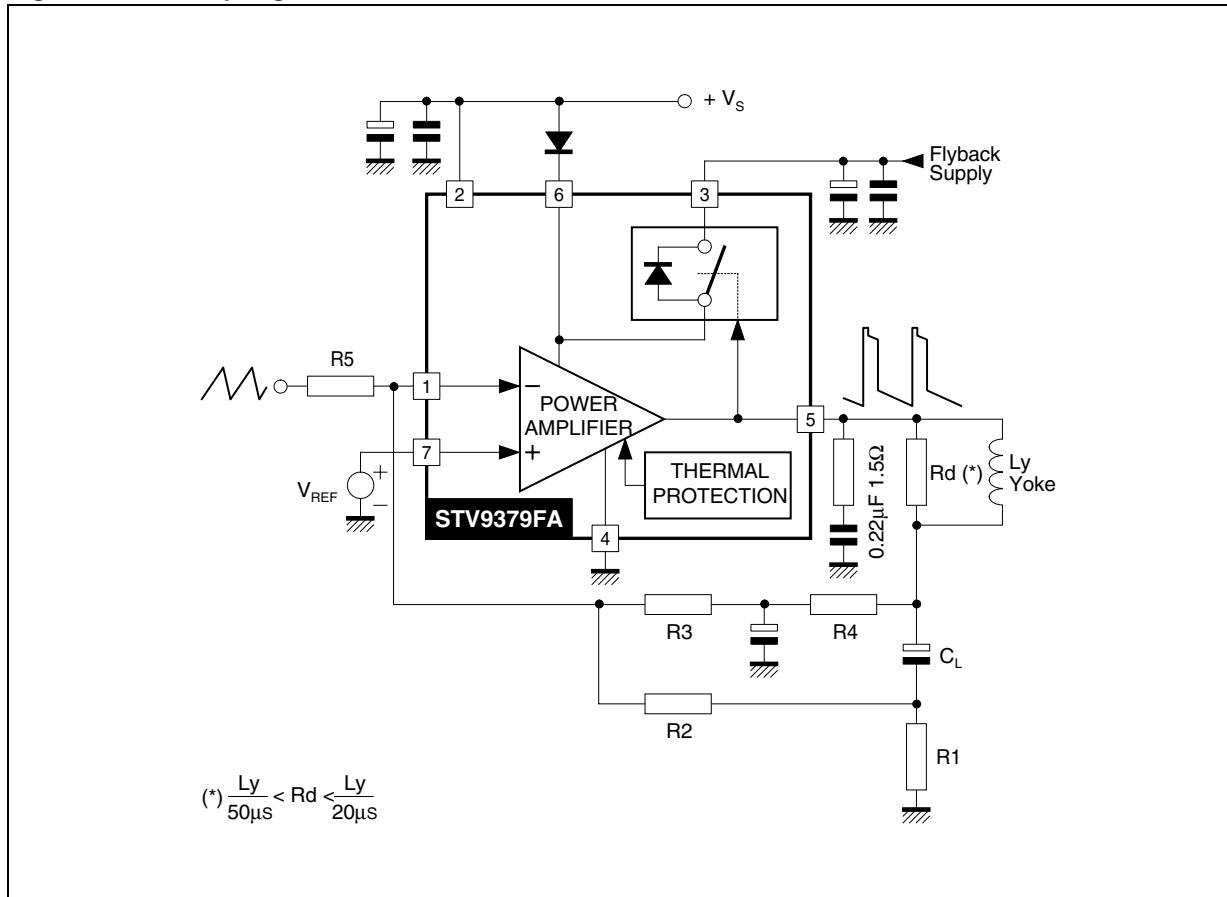
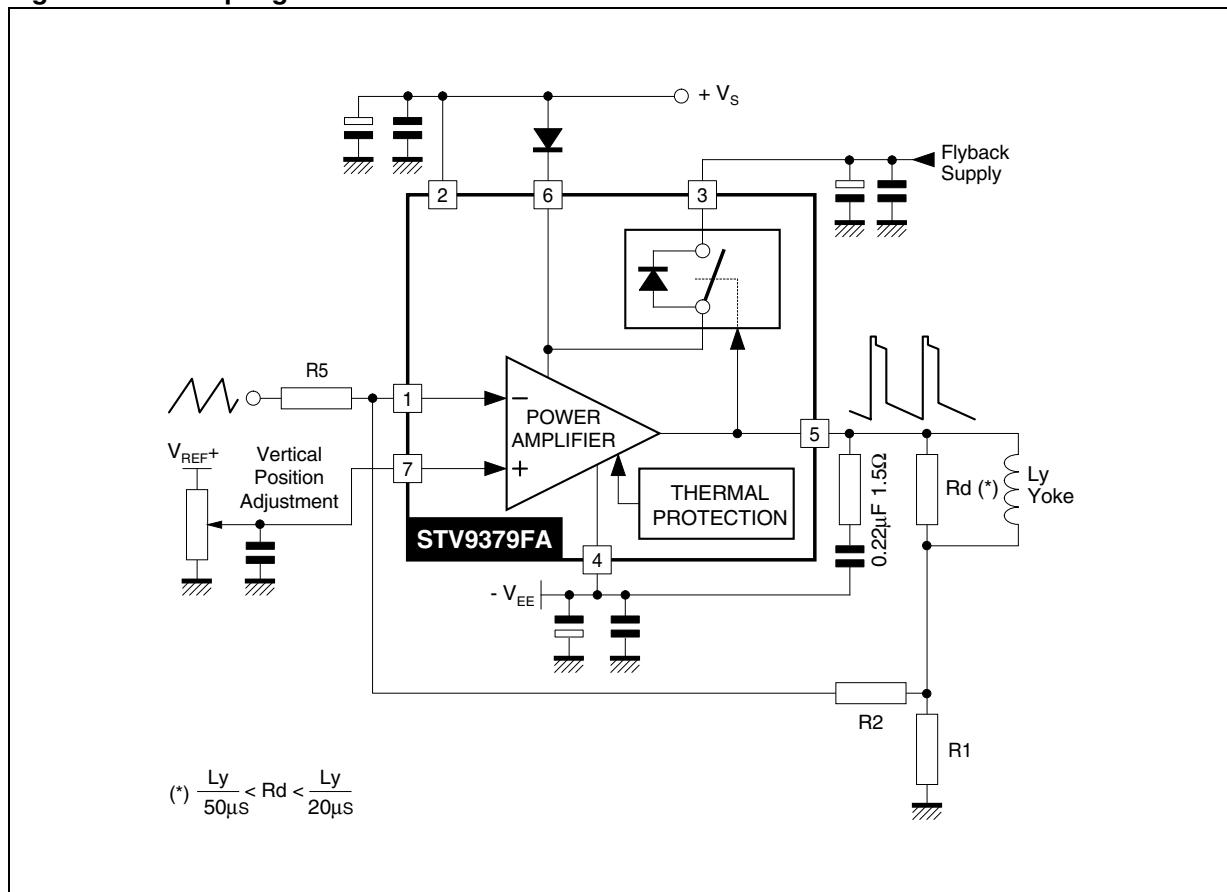
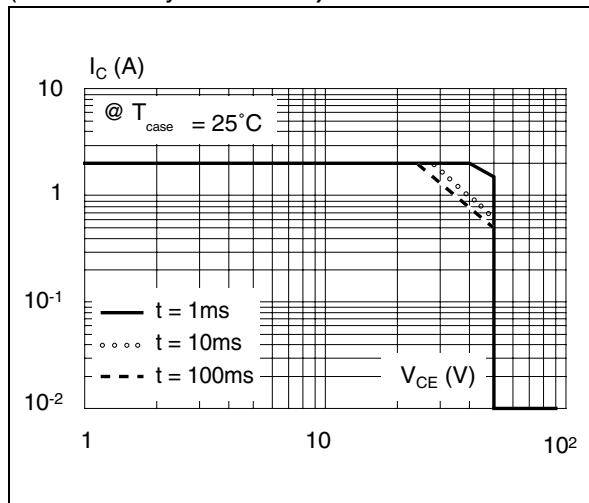
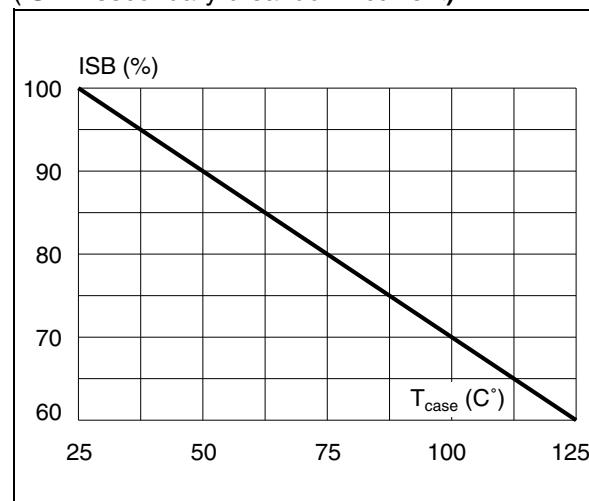


Figure 5. DC Coupling**Figure 6. Output Transistors SOA**
(for secondary breakdown)**Figure 7. Secondary Breakdown Temperature Derating Curve**
(ISB = secondary breakdown current)

STV9379FA

PART NUMBERING

Table 4. Order Codes

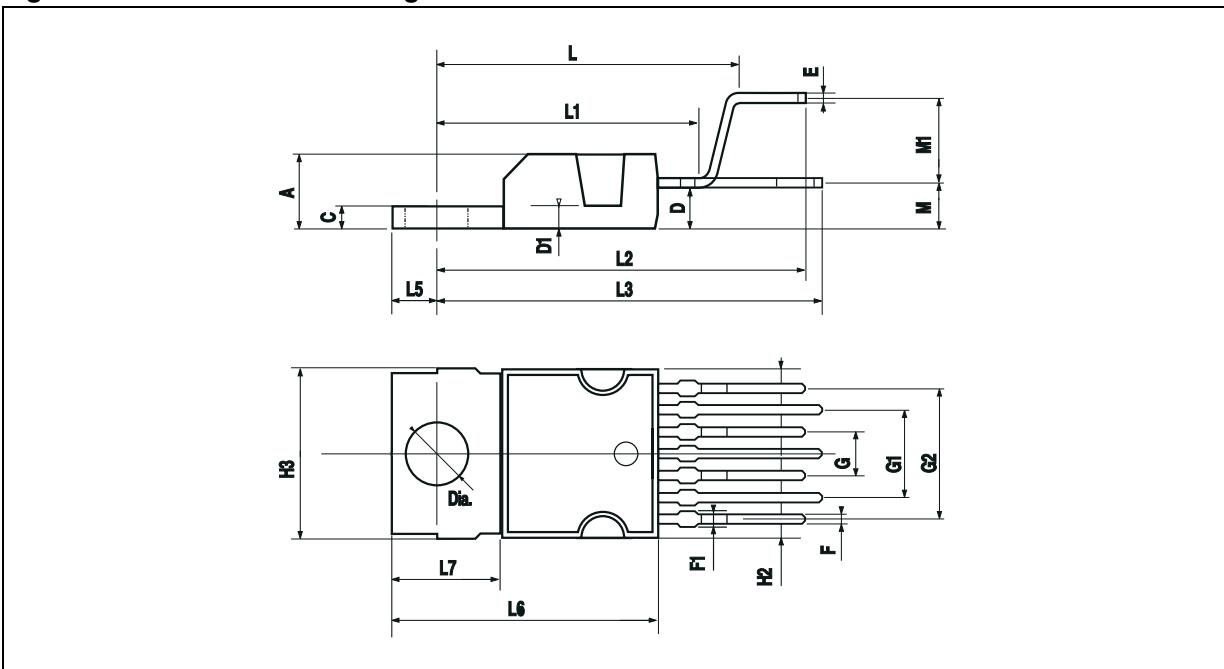
Part Number	Package	Temperature Range
STV9379FA	HEPTAWATT7	-25 to 85 °C

PACKAGE MECHANICAL

Table 5. HEPTAWATT7 - Mechanical Data

Symbol	millimeters			inches		
	Typ	Min	Max	Typ	Min	Max
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.6		0.8	0.024		0.031
F1			0.9			0.035
G	2.41	2.54	2.67	0.095	0.100	0.105
G1	4.91	5.08	5.21	0.193	0.200	0.205
G2	7.49	7.62	7.8	0.295	0.300	0.307
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L		16.97			0.668	
L1		14.92			0.587	
L2		21.54			0.848	
L3		22.62			0.891	
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
M		2.8			0.110	
M1		5.08			0.200	
Dia.	3.65		3.85	0.144		0.152

Figure 8. HEPTAWATT7 - Package Dimensions



Note: Drawing is not to scale

STV9379FA

REVISION HISTORY

Table 6. Revision History

Date	Revision	Description of Changes
June-1998	1	First Issue
14-Apr-2004	2	Stylesheet update. No content change.

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